

March 2013

## FDPF7N50U

# N-Channel UniFET<sup>TM</sup> Ultra FRFET<sup>TM</sup> MOSFET

**500 V, 5 A, 1.5** Ω

#### **Features**

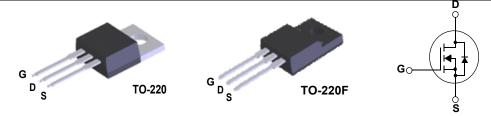
- $R_{DS(on)} = 1.5 \Omega \text{ (Max.)} @ V_{GS} = 10 \text{ V, } I_D = 2.5 \text{ A}$
- Low Gate Charge (Typ.12.8 nC)
- Low C<sub>rss</sub> (Typ. 9 pF)
- 100% Avalanche Tested
- · Improved dv/dt Capability

## **Applications**

- LCD/LED TV
- · Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supply

## **Description**

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor<sup>®</sup>'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. UniFET Ultra FRFET<sup>TM</sup> MOSFET has much superior body diode reverse recovery performance. Its t<sub>rr</sub> is less than 50nsec and the reverse dv/dt immunity is 20V/nsec while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore UniFET Ultra FRFET MOSFET can remove additional component and improve system reliability in certain applications that require performance improvement of the MOSFET's body diode. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



## **Absolute Maximum Ratings**

Symbol	Parameter		FDPF7N50U	Unit	
V <sub>DSS</sub>	Drain-Source Voltage		500	V	
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25°C) - Continuous (T <sub>C</sub> = 100°C)		5 * 3.0 *	A A
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	20 *	Α
V <sub>GSS</sub>	Gate-Source voltage			±30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	125	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	5	А
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	8.9	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	20	V/ns
P <sub>D</sub>	Power Dissipation	(T <sub>C</sub> = 25°C) - Derate above 25°C		31.3 0.25	W/°C
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C	
T <sub>L</sub>	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		300	°C	

<sup>\*</sup> Drain current limited by maximum junction temperature.

## **Thermal Characteristics**

Symbol	Parameter	FDPF7N50U	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	4.0	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5		

## **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Package	Reel Size	Tape Width	Quantity
FDPF7N50U	FDPF7N50U	TO-220F		-	50

## $\textbf{Electrical Characteristics} \quad \textbf{T}_{\text{C}} = 25^{\circ}\text{C unless otherwise noted}$

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	teristics	1	I			ı
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage $V_{GS} = 0V$ , $I_D = 250\mu A$		500			V
$\Delta BV_{DSS} \ \Delta T_{J}$	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250μA, Referenced to 25°C		0.5		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 400V, T <sub>C</sub> = 125°C			25 250	μ <b>Α</b> μ <b>Α</b>
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30V, V <sub>DS</sub> = 0V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS} = -30V$ , $V_{DS} = 0V$			-100	nA
On Charac	teristics		•			
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 2.5A		1.2	1.5	Ω
9 <sub>FS</sub>	Forward Transconductance $V_{DS} = 40V, I_D = 2.5A$			2.5		S
Dynamic C	haracteristics	•				
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V,		720	940	pF
C <sub>oss</sub>	Output Capacitance	f = 1.0MHz		95	190	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			9	13.5	pF
Switching	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = 250V, I_{D} = 5A$		6	20	ns
t <sub>r</sub>	Turn-On Rise Time	$R_G = 25\Omega$		55	120	ns
$t_{d(off)}$	Turn-Off Delay Time			25	60	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)		35	80	ns
$Q_g$	Total Gate Charge	V <sub>DS</sub> = 400V, I <sub>D</sub> = 5A		12.8	16.6	nC
$Q_{gs}$	Gate-Source Charge	V <sub>GS</sub> = 10V		3.7		nC
$Q_{gd}$	Gate-Drain Charge	(Note 4)		5.8		nC
Drain-Sour	ce Diode Characteristics and Maximur	n Ratings	ı			
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				5	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				20	Α
$V_{SD}$	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 5A			1.6	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0V, I <sub>S</sub> = 5A		40		ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI <sub>F</sub> /dt =100A/μs		0.04		μС

#### NOTES

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. I $_{AS}$  = 5A, V $_{DD}$  = 50V, L=10mH, R $_{G}$  = 25 $\Omega$ , Starting T $_{J}$  = 25 $^{\circ}$ C
- 3.  $I_{SD} \le$  5A, di/dt  $\le$  200A/ $\mu$ s,  $V_{DD} \le$  BV $_{DSS}$ , Starting  $T_J$  = 25°C
- 4. Essentially Independent of Operating Temperature Typical Characteristics

## **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

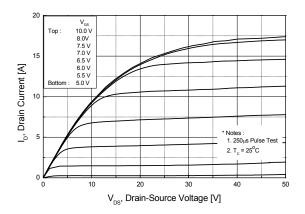


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

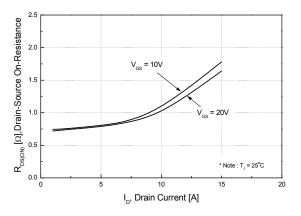
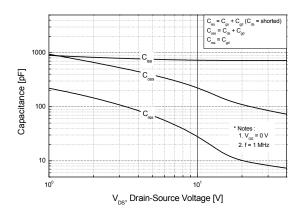


Figure 5. Capacitance Characteristics



**Figure 2. Transfer Characteristics** 

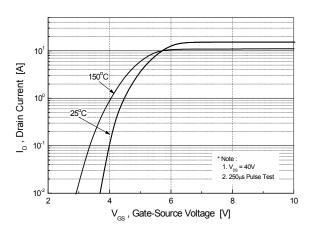


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

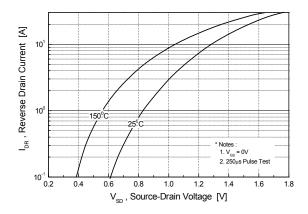
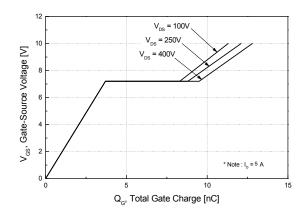


Figure 6. Gate Charge Characteristics



## **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

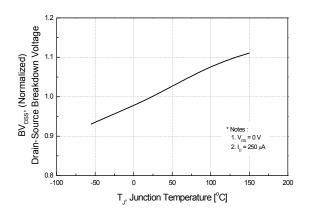


Figure 8. Maximum Drain Current Vs. Case Temperature

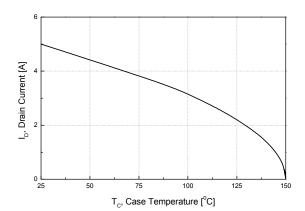


Figure 9. Maximum Safe Operating Area - FDPF7N50U

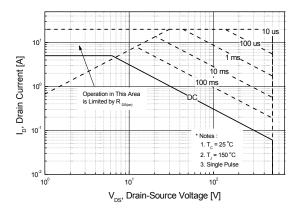
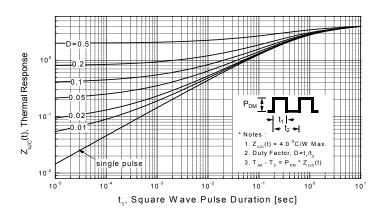
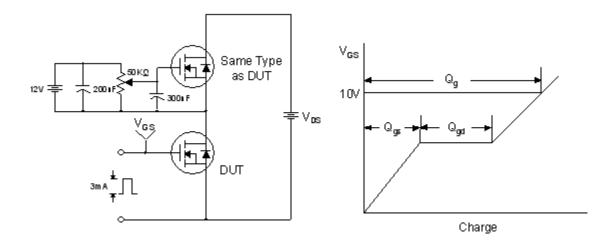


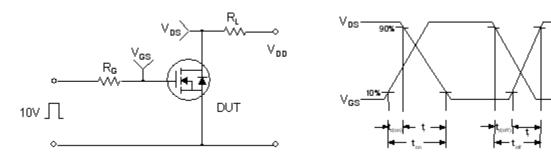
Figure 10. Transient Thermal Response Curve



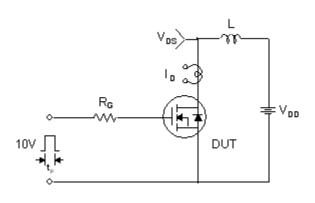
### **Gate Charge Test Circuit & Waveform**

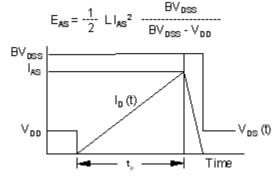


## **Resistive Switching Test Circuit & Waveforms**

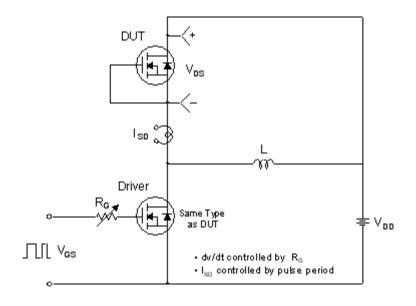


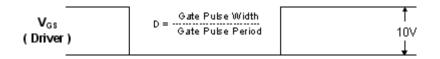
### **Unclamped Inductive Switching Test Circuit & Waveforms**

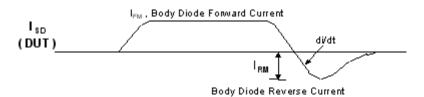


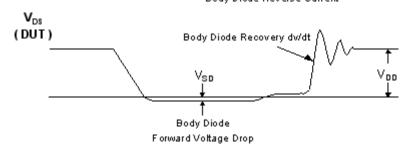


### Peak Diode Recovery dv/dt Test Circuit & Waveforms









## **Mechanical Dimensions** TO-220M03 2.742.34 10.36 Α 9.96 Ø 3.28 7.00 3.40 3.08 0.70 3.20 SEE NOTE "F" SEE NOTE "F" 6.88 6.48 (+)1 X 45° 16.07 15.67 16.00 15.60 (3.23) B 3 1.47 2.96 1.24 2.14 2.56 0.90 10.05 0.70 9.45 $\oplus$ 0.50 M A 30° 0.45 0.60 0.25 0.45 2.54 2.54 NOTES: A. EXCEPT WHERE NOTED CONFORMS TO EIAJ SC91A. B DOES NOT COMPLY EIAJ STD. VALUE. C. ALL DIMENSIONS ARE IN MILLIMETERS. D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TE BAR PROTRUSIONS. 4.90 <u>/</u>B\ 4.50 E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994 F. OPTION 1 - WITH SUPPORT PIN HOLE. OPTION 2 - NO SUPPORT PIN HOLE. G. DRAWING FILE NAME: TO220M03REV3 **Dimensions in Millimeters**





#### **TRADEMARKS**

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

2Cool™ FPS™ F-PFS™ AccuPower™ AX-CAP<sup>®</sup> BitSiC™ FRFET® Global Power Resource<sup>SM</sup> Build it Now™ Green Bridge™ CorePLUS™ Green FPS™ CorePOWER™ Green FPS™ e-Series™  $CROSSVOLT^{\text{TM}}$ Gmax™ GTO™

Current Transfer Logic™ IntelliMAX™ DEUXPEED® ISOPLANAR™ Dual Cool™ Marking Small Speakers Sound Louder

EcoSPARK® and Better™ EfficentMax™ MegaBuck™ ESBC™ MICROCOUPLER™ MicroFET™ MicroPak™

MicroPak2™ Fairchild<sup>®</sup> MillerDrive™ Fairchild Semiconductor® MotionMax™ FACT Quiet Series™ mWSaver™ FACT<sup>®</sup> FAST® OptoHiT™ OPTOLOGIC® FastvCore™ OPTOPLANAR® FETBench™

PowerTrench® PowerXS™

Programmable Active Droop™

QFET® QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™ SignalWise™

SmartMax™ SMART START™

Solutions for Your Success™

STEALTH™ SuperFET®

SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™

Sync-Lock™

SYSTEM ®' GENERAL TinyBoost<sup>T</sup> TinyBuck™ TinyCalc™ TinyLogic<sup>®</sup>
TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC®

TriFault Detect™ TRUECURRENT®\* μSerDes™

UHC® Ultra FRFET™ UniFET™ VCX™ VisualMax™ VoltagePlus™ XSTM

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN, NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN. WHICH COVERS THESE PRODUCTS.

**LIFE SUPPORT POLICY**FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their

parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification Product Status		Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor:

FDPF7N50U\_G